



LM2765 Switched-Capacitor Voltage Converter

1 Features

- Doubles Input Supply Voltage
- SOT-23 6-Pin Package
- 20-Ω Typical Output Impedance
- 90% Typical Conversion Efficiency at 20 mA
- 0.1-μA Typical Shutdown Current

2 Applications

- Cellular Phones
- Pagers
- PDAs
- Operational Amplifier Power Supplies
- Interface Power Supplies
- Handheld Instruments

3 Description

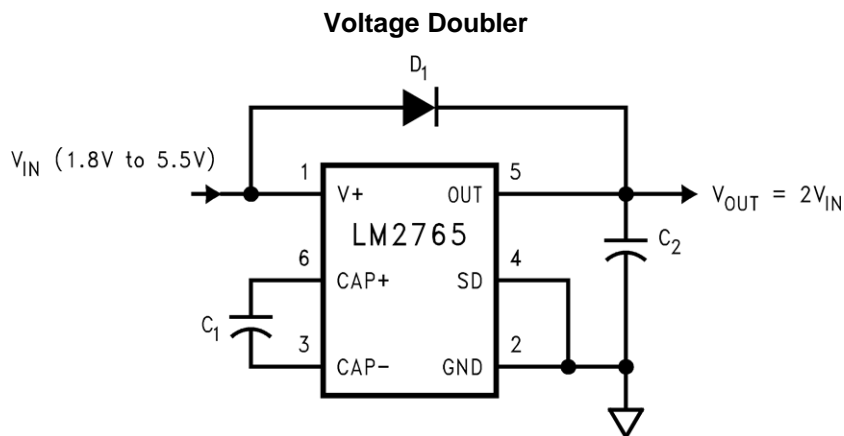
The LM2765 CMOS charge-pump voltage converter operates as a voltage doubler for an input voltage in the range of 1.8 V to 5.5 V. Two low-cost capacitors and a diode are used in this circuit to provide up to 20 mA of output current.

The LM2765 operates at 50-kHz switching frequency to reduce output resistance and voltage ripple. With an operating current of only 130 μA (operating efficiency greater than 90% with most loads) and 0.1-μA typical shutdown current, the LM2765 provides ideal performance for battery powered systems. The device is manufactured in a 6-pin SOT-23 package.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)
LM2765	SOT-23 (6)	2.90 mm × 1.60 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.



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4 Revision History

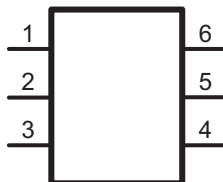
NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision C (May 2013) to Revision D	Page
• Added <i>Pin Configuration and Functions</i> section, <i>ESD Rating</i> table, <i>Feature Description</i> , <i>Device Functional Modes</i> , <i>Application and Implementation</i> , <i>Power Supply Recommendations</i> , <i>Layout</i> , <i>Device and Documentation Support</i> , and <i>Mechanical, Packaging, and Orderable Information</i> sections; change pin name "VOUT" to "OUT".....	1
• Added top nav icon for TI design	1
• Changed $R_{\theta JA}$ value from 210°C/W to 185.2°C/W; add additional thermal values	4

Changes from Revision B (May 2013) to Revision C	Page
• Changed layout of National Semiconductor data sheet to TI format.....	12

5 Pin Configuration and Functions

**DBV Package
6-Pin SOT-23
Top View**



Pin Functions

PIN		TYPE	DESCRIPTION
NO.	NAME		
1	V+	Power	Power supply positive voltage input
2	GND	Ground	Power supply ground input
3	CAP–	Power	Connect this pin to the negative terminal of the charge-pump capacitor.
4	SD	Input	Shutdown control pin; tie this pin to ground in normal operation.
5	OUT	Power	Positive voltage output
6	CAP+	Power	Connect this pin to the positive terminal of the charge-pump capacitor.

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾⁽²⁾

	MIN	MAX	UNIT
Supply voltage (V+ to GND or V+ to OUT)		5.8	V
SD	(GND – 0.3 V)	(V+ + 0.3 V)	
OUT continuous output current		40	mA
Output short-circuit duration to GND ⁽³⁾		1	sec
Continuous power dissipation (T _A = 25°C) ⁽⁴⁾		600	mW
T _{J-MAX} ⁽⁴⁾		150	°C
Storage temperature, T _{stg}	–65	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) If Military/Aerospace specified devices are required, contact the Texas Instruments Sales Office/ Distributors for availability and specifications.
- (3) OUT may be shorted to GND for one second without damage. However, shorting OUT to V+ may damage the device and must be avoided. Also, for temperatures above 85°C, OUT must not be shorted to GND or V+, or device may be damaged.
- (4) The maximum allowable power dissipation is calculated by using $P_{D-MAX} = (T_{J-MAX} - T_A)/R_{\theta JA}$, where T_{J-MAX} is the maximum junction temperature, T_A is the ambient temperature, and R_{θJA} is the junction-to-ambient thermal resistance of the specified package.

6.2 ESD Ratings

		VALUE	UNIT
V _(ESD) Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±2000	V
	Machine model	200	V

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

	MIN	NOM	MAX	UNIT
Ambient temperature	–40		85	°C
Junction temperature	–40		100	°C

6.4 Thermal Information

THERMAL METRIC ⁽¹⁾		LM2765	UNIT
		DBV (SOT-23)	
		6 PINS	
R _{θJA}	Junction-to-ambient thermal resistance	185.2	°C/W
R _{θJC(top)}	Junction-to-case (top) thermal resistance	131.5	°C/W
R _{θJB}	Junction-to-board thermal resistance	34.8	°C/W
ψ _{JT}	Junction-to-top characterization parameter	21.6	°C/W
ψ _{JB}	Junction-to-board characterization parameter	34.1	°C/W

- (1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report.

6.5 Electrical Characteristics

MIN and MAX limits apply over the full operating temperature range. Unless otherwise specified: $T_J = 25^\circ\text{C}$, $V_+ = 5\text{ V}$, $C_1 = C_2 = 3.3\text{ }\mu\text{F}$.⁽¹⁾

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V+	Supply voltage		1.8		5.5	V
I _Q	Supply current	No load		130	450	μA
I _{SD}	Shutdown supply current			0.1	0.5	μA
		T _A = 85°C		0.2		
V _{SD}	Shutdown pin input voltage	Shutdown mode	2			V
		Normal operation			0.6	
I _L	Output current	2.5 V ≤ V _{IN} ≤ 5.5 V	20			mA
		1.8 V ≤ V _{IN} ≤ 2.5 V	10			
R _{OUT}	Output resistance ⁽²⁾	I _L = 20 mA		20	40	Ω
f _{OSC}	Oscillator frequency	See ⁽³⁾	40	100	200	kHz
f _{SW}	Switching frequency	See ⁽³⁾	20	50	100	kHz
P _{EFF}	Power efficiency	R _L (1 kΩ) between GND and OUT		92%		
V _{OEFF}	Voltage conversion efficiency	No load		99.96%		

- (1) In the test circuit, capacitors C_1 and C_2 are 3.3- μF , 0.3- Ω maximum ESR capacitors. Capacitors with higher ESR increase output resistance, reduce output voltage, and efficiency.
- (2) Specified output resistance includes internal switch resistance and capacitor ESR. See the details in [Application and Implementation](#) for simple negative voltage converter.
- (3) The output switches operate at one half of the oscillator frequency, $f_{OSC} = 2f_{SW}$.

6.6 Typical Characteristics

(Circuit of [Test Circuit](#), $V_{IN} = 5\text{ V}$, $T_A = 25^\circ\text{C}$ unless otherwise specified)

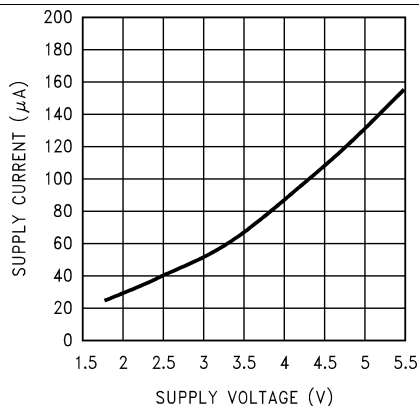


Figure 1. Supply Current vs Supply Voltage

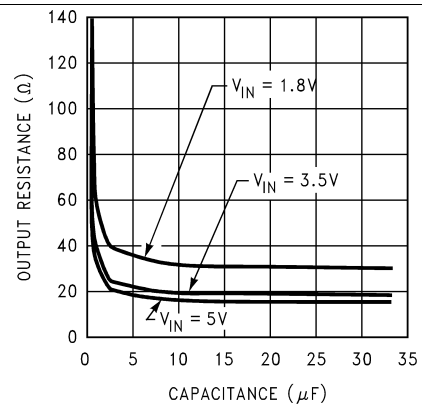


Figure 2. Output Resistance vs Capacitance

Typical Characteristics (continued)

(Circuit of [Test Circuit](#), $V_{IN} = 5V$, $T_A = 25^\circ C$ unless otherwise specified)

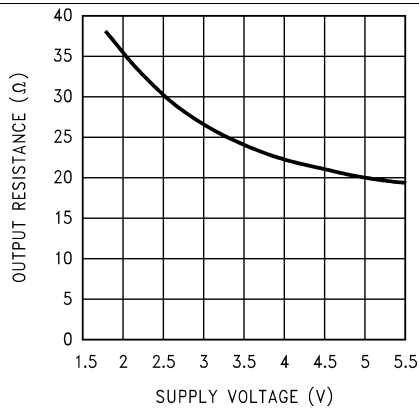


Figure 3. Output Resistance vs Supply Voltage

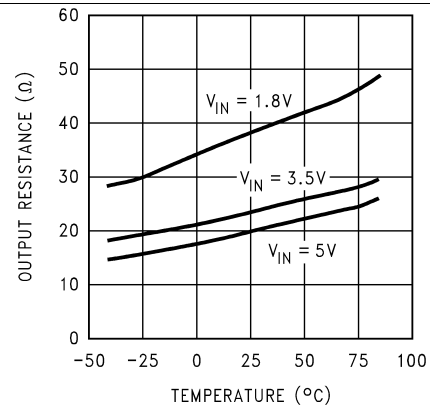


Figure 4. Output Resistance vs Temperature

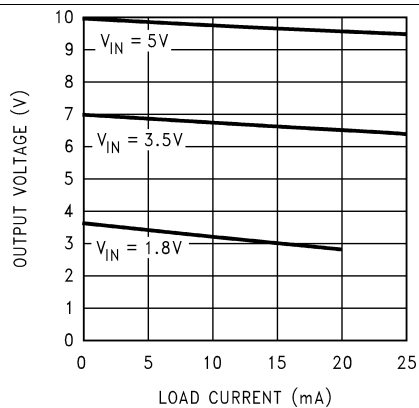


Figure 5. Output Voltage vs Load Current

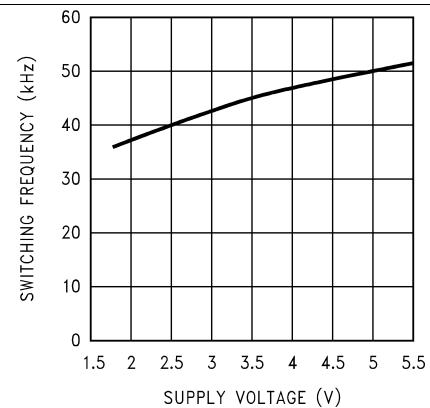


Figure 6. Switching Frequency vs Supply Voltage

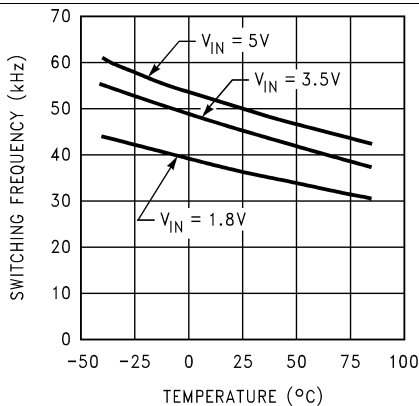


Figure 7. Switching Frequency vs Temperature

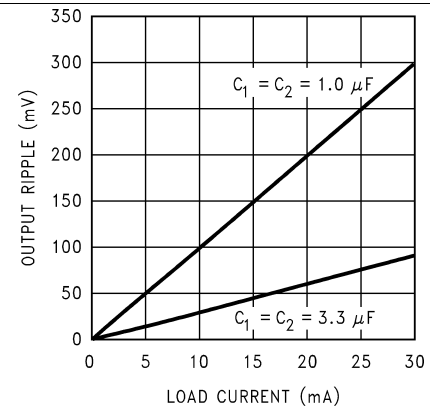
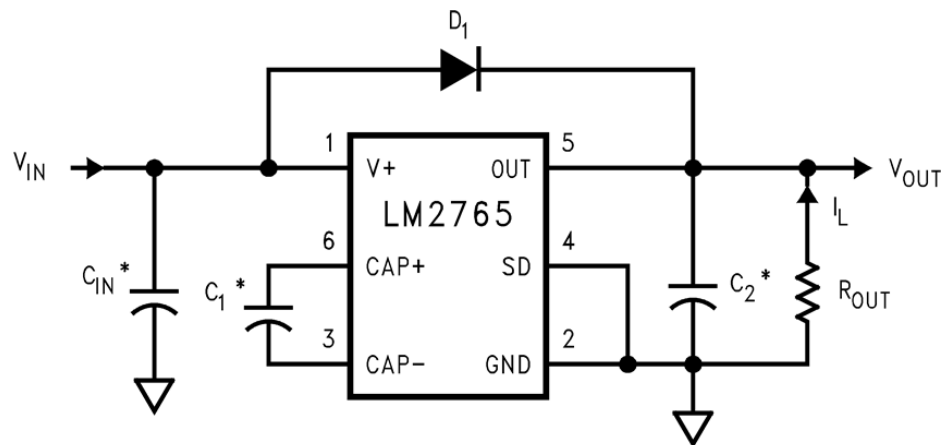


Figure 8. Output Ripple vs Load Current

7 Parameter Measurement Information

7.1 Test Circuit



* C_{IN} , C_1 , and C_2 are $3.3\ \mu\text{F}$ OS-CON capacitors.

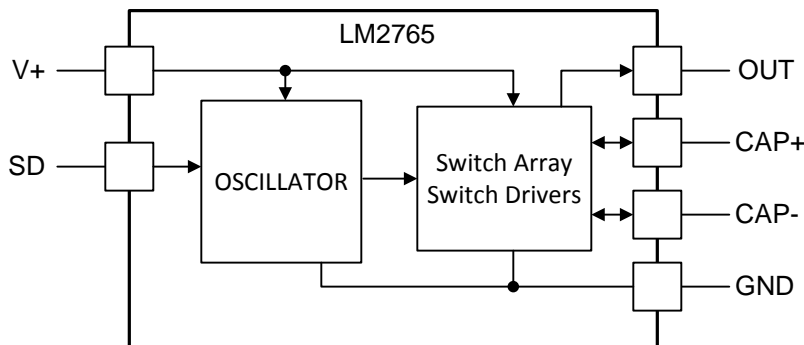
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8 Detailed Description

8.1 Overview

The LM2765 CMOS charge-pump voltage converter operates as a voltage doubler for an input voltage in the range of 1.8 V to 5.5 V. Two low-cost capacitors and a diode (needed during start-up) are used in this circuit to provide up to 20 mA of output current.

8.2 Functional Block Diagram



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8.3 Feature Description

8.3.1 Circuit Description

The LM2765 contains four large CMOS switches which are switched in a sequence to double the input supply voltage. Energy transfer and storage are provided by external capacitors. [Figure 9](#) shows the voltage conversion scheme. When S_2 and S_4 are closed, C_1 charges to the supply voltage V_+ . During this time interval, switches S_1 and S_3 are open. In the next time interval, S_2 and S_4 are open; at the same time, S_1 and S_3 are closed, the sum of the input voltage V_+ and the voltage across C_1 gives the $2 V_+$ output voltage when there is no load. The output voltage drop when a load is added is determined by the parasitic resistance ($R_{ds(on)}$ of the MOSFET switches and the ESR of the capacitors) and the charge transfer loss between capacitors. See [Application and Implementation](#) for more details.

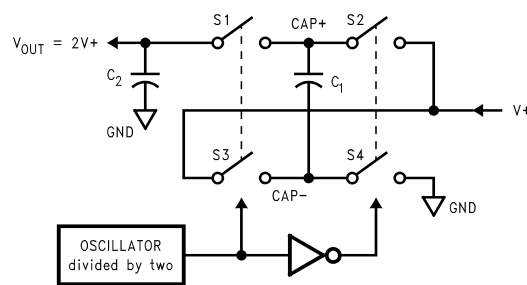


Figure 9. Voltage Doubling Principle

8.4 Device Functional Modes

8.4.1 Shutdown Mode

A shutdown (SD) pin is available to disable the device and reduce the quiescent current to 1 μ A. In normal operating mode, the SD pin is connected to ground. The device can be brought into the shutdown mode by applying to the SD pin a voltage greater than 40% of the V_+ pin voltage.

9 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers must validate and test their design implementation to confirm system functionality.

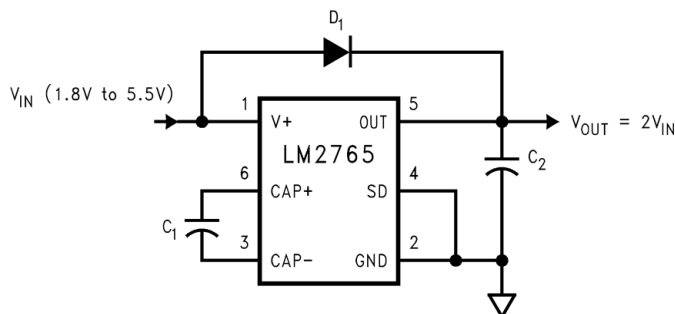
9.1 Application Information

The LM2765 provides a simple and efficient means of creating an output voltage level equal to twice that of the input voltage. Without the need of an inductor, the application solution size can be reduced versus the magnetic DC-DC converter solution.

9.2 Typical Applications

9.2.1 Voltage Doubler

The main application of the LM2765 is to double the input voltage. The range of the input supply voltage is 1.8 V to 5.5 V.



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Figure 10. Voltage Doubler

9.2.1.1 Design Requirements

Example requirements for LM2765 device applications:

DESIGN PARAMETER	EXAMPLE VALUE
Input voltage range	1.8 V to 5.5 V
Output current	0 mA to 20 mA
Boost switching frequency	20 kHz

9.2.1.2 Detailed Design Requirements

9.2.1.2.1 Positive Voltage Doubler

The output characteristics of this circuit can be approximated by an ideal voltage source in series with a resistance. The voltage source equals $2V+$. The output resistance R_{OUT} is a function of the ON resistance of the internal MOSFET switches, the oscillator frequency, the capacitance and equivalent series resistance (ESR) of C_1 and C_2 . Since the switching current charging and discharging C_1 is approximately twice as the output current, the effect of the ESR of the pumping capacitor C_1 will be multiplied by four in the output resistance. The output capacitor C_2 is charging and discharging at a current approximately equal to the output current, therefore, its ESR only counts when in the output resistance. A good approximation of R_{OUT} is:

$$R_{OUT} \cong 2R_{SW} + \frac{2}{f_{OSC} \times C_1} + 4ESR_{C1} + ESR_{C2}$$

where

- R_{SW} is the sum of the ON resistance of the internal MOSFET switches shown in [Figure 9](#). R_{SW} is typically $8\ \Omega$ for the LM2765. (1)

The peak-to-peak output voltage ripple is determined by the oscillator frequency, the capacitance and ESR of the output capacitor C_2 :

$$V_{RIPPLE} = \frac{I_L}{f_{OSC} \times C_2} + 2 \times I_L \times ESR_{C2} \quad (2)$$

High capacitance, low-ESR capacitors can reduce both the output resistance and the voltage ripple.

The Schottky diode D_1 is only needed for start-up. The internal oscillator circuit uses the OUT pin and the GND pin. Voltage across OUT and GND must be larger than 1.8 V to insure the operation of the oscillator. During start-up, D_1 is used to charge up the voltage at the OUT pin to start the oscillator; also, it protects the device from turning-on its own parasitic diode and potentially latching-up. Therefore, the Schottky diode D_1 must have enough current carrying capability to charge the output capacitor at start-up, as well as a low forward voltage to prevent the internal parasitic diode from turning-on. A Schottky diode such as 1N5817 can be used for most applications. If the input voltage ramp is less than 10 V/ms, a smaller Schottky diode such as MBR0520LT1 can be used to reduce the circuit size.

9.2.1.2.2 Capacitor Selection

As discussed in [Positive Voltage Doubler](#), the output resistance and ripple voltage are dependent on the capacitance and ESR values of the external capacitors. The output voltage drop is the load current times the output resistance, and the power efficiency is:

$$\eta = \frac{P_{OUT}}{P_{IN}} = \frac{I_L^2 R_L}{I_L^2 R_L + I_L^2 R_{OUT} + I_Q(V+)}$$

where

- $I_Q(V+)$ is the quiescent power loss of the device; and
- $I_L^2 R_{OUT}$ is the conversion loss associated with the switch on-resistance, the two external capacitors and their ESRs. (3)

The selection of capacitors is based on the specifications of the dropout voltage (which equals $I_{OUT} R_{OUT}$), the output voltage ripple, and the converter efficiency. Low ESR capacitors are recommended to maximize efficiency, reduce the output voltage drop and voltage ripple.

9.2.1.2.3 Paralleling Devices

Any number of LM2765 devices can be paralleled to reduce the output resistance. Each device must have its own pumping capacitor C_1 , while only one output capacitor, C_{OUT} , is required as shown in [Figure 11](#). The composite output resistance is:

$$R_{OUT} = R_{OUT} \text{ of each LM2765} / \text{number of devices} \quad (4)$$

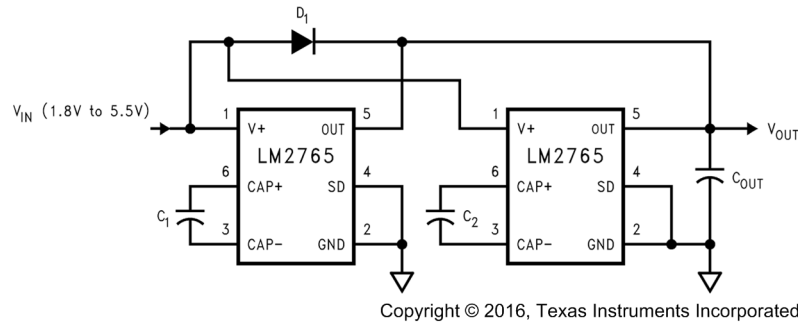


Figure 11. Lowering Output Resistance by Paralleling Devices

9.2.1.2.4 Cascading Devices

Cascading the LM2765 devices is an easy way to produce a greater voltage (a two-stage cascade circuit is shown in Figure 12).

The effective output resistance is equal to the weighted sum of each individual device, shown in Equation 5:

$$R_{OUT} = 1.5 R_{OUT_1} + R_{OUT_2} \quad (5)$$

Note that the increasing of the number of cascading stages is practically limited since it significantly reduces the efficiency, increases the output resistance and output voltage ripple.

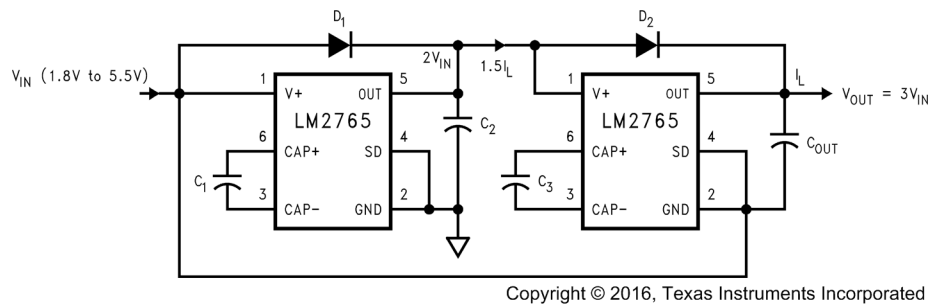


Figure 12. Increasing Output Voltage by Cascading Devices

9.2.1.2.5 Regulating V_OUT

It is possible to regulate the output of the LM2765 by use of a low dropout regulator (such as LP2980-5.0). The whole converter is depicted in Figure 13.

A different output voltage is possible by use of LP2980-3.3, LP2980-3.0, or LP2980-ADJ.

Note that the following conditions must be satisfied simultaneously for worst-case design:

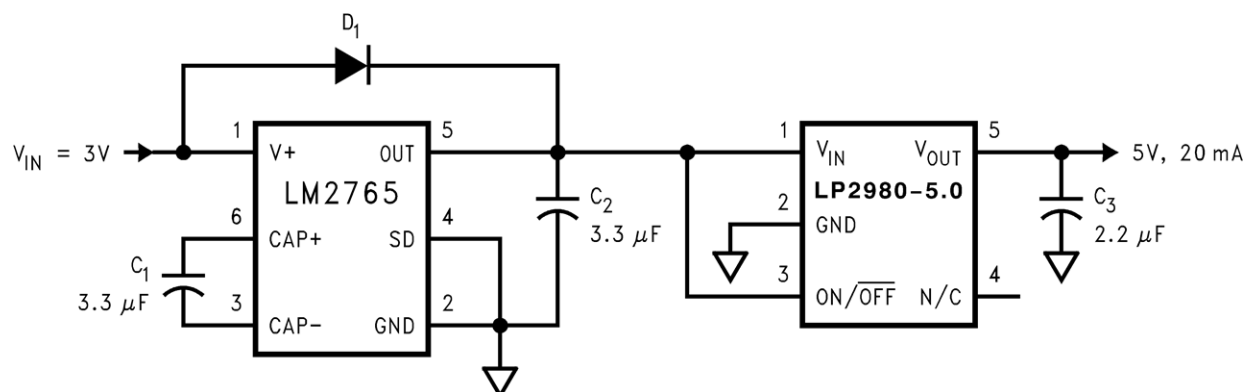
$$2V_{in_min} > V_{out_min} + V_{drop_max} (LP2980) + I_{out_max} \times R_{out_max} (LM2765) \quad (6)$$

$$2V_{in_max} < V_{out_max} + V_{drop_min} (LP2980) + I_{out_min} \times R_{out_min} (LM2765) \quad (7)$$

LM2765

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Figure 13. Generating a Regulated +5-V From +3-V Input Voltage

9.2.1.3 Application Curve

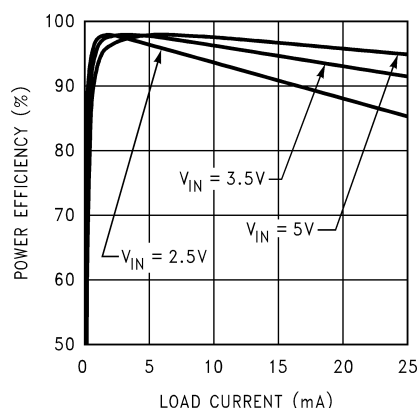


Figure 14. Efficiency vs Load Current

10 Power Supply Recommendations

The LM2765 is designed to operate from as an inverter over an input voltage supply range between 1.8 V and 5.5 V. This input supply must be well regulated and capable to supply the required input current. If the input supply is located far from the device, additional bulk capacitance may be required in addition to the ceramic bypass capacitors.

11 Layout

11.1 Layout Guidelines

The high switching frequency and large switching currents of the LM2765 make the choice of layout important. Use the following steps as a reference to ensure the device is stable and maintains proper LED current regulation across its intended operating voltage and current range.

- Place C_{IN} on the top layer (same layer as the LM2765) and as close as possible to the device. Connecting the input capacitor through short, wide traces to both the V+ and GND pins reduces the inductive voltage spikes that occur during switching which can corrupt the V+ line.
- Place C_{OUT} on the top layer (same layer as the LM2765) and as close as possible to the OUT and GND pin. The returns for both C_{IN} and C_{OUT} must come together at one point, as close as possible to the GND pin. Connecting C_{OUT} through short, wide traces reduce the series inductance on the OUT and GND pins that can corrupt the V_{OUT} and GND lines and cause excessive noise in the device and surrounding circuitry.
- Place C1 on the top layer (same layer as the LM2765 device) and as close as possible to the device. Connect the flying capacitor through short, wide traces to both the CAP+ and CAP– pins.

11.2 Layout Example

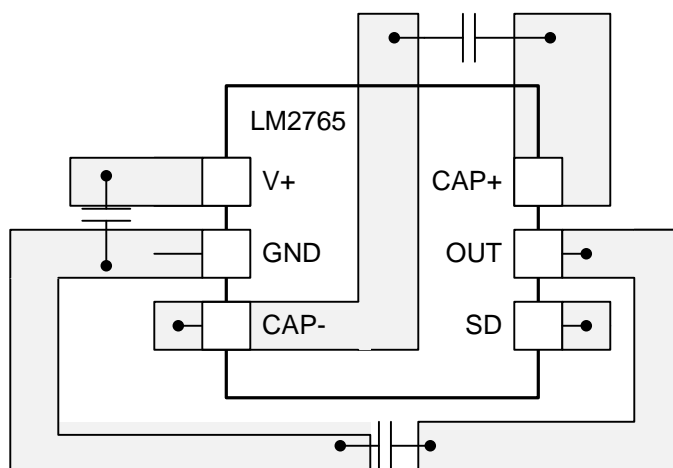


Figure 15. Typical Layout for LM2765

12 Device and Documentation Support

12.1 Device Support

12.1.1 Third-Party Products Disclaimer

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12.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

12.3 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

TI E2E™ Online Community *TI's Engineer-to-Engineer (E2E) Community*. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

12.4 Trademarks

E2E is a trademark of Texas Instruments.
All other trademarks are the property of their respective owners.

12.5 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

12.6 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
LM2765M6X/NOPB	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 85	S15B
LM2765M6X/NOPB.A	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 85	S15B
LM2765M6X/NOPB.B	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 85	S15B

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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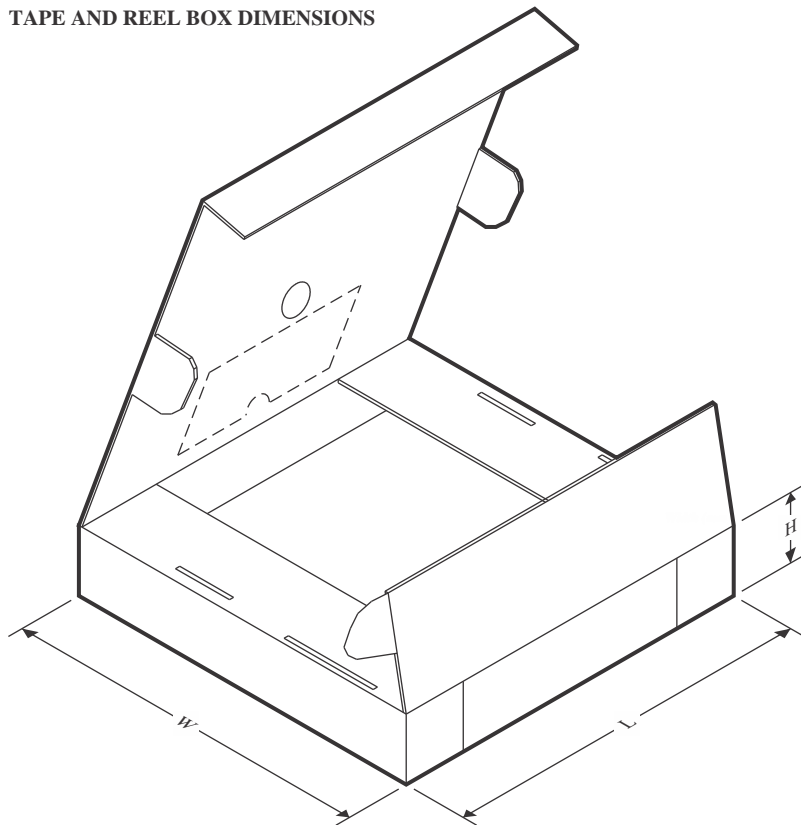
TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LM2765M6X/NOPB	SOT-23	DBV	6	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LM2765M6X/NOPB	SOT-23	DBV	6	3000	210.0	185.0	35.0

EXAMPLE BOARD LAYOUT

DBV0006A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X



SOLDER MASK DETAILS

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NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DBV0006A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:15X

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NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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